



High-Speed Quad SPST CMOS Analog Switch

FEATURES

- Fast Switching— t_{ON} : 38 ns
- Low On-Resistance: 25 Ω
- Low Leakage: 100 pA
- Low Charge Injection
- TTL/CMOS Logic Compatible
- Single Supply Compatibility
- High Current Rating: -30 mA

BENEFITS

- Faster Throughput
- Higher Accuracy
- Reduced Pedestal Error
- Upgrades Existing Designs
- Simple Interfacing
- Replaces HI201HS, ADG201HS
- Space Savings (TSSOP)

APPLICATIONS

- Data Acquisition
- Hi-Rel Systems
- Sample-and-Hold Circuits
- Communication Systems
- Automatic Test Equipment
- Integrator Reset Circuits
- Choppers
- Gain Switching
- Avionics

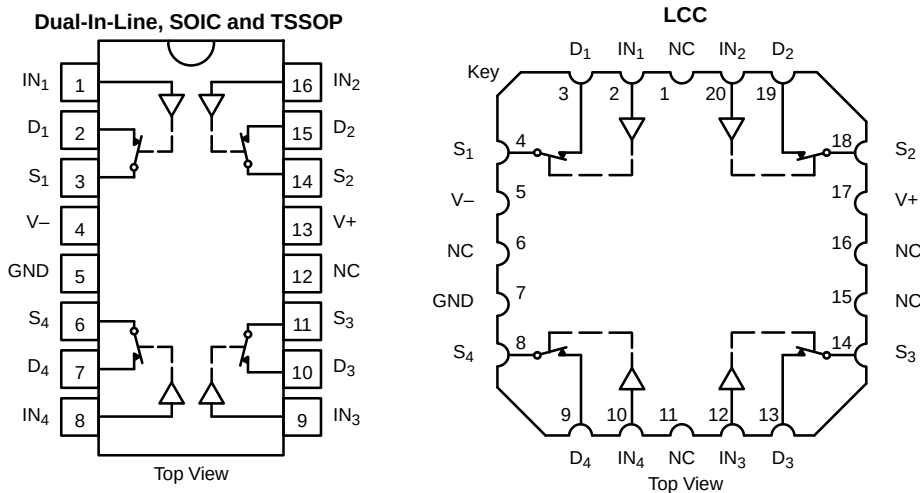
DESCRIPTION

The DG201HS is an improved monolithic device containing four independent analog switches. It is designed to provide high speed, low error switching of analog signals. Combining low on-resistance (25 Ω) with high speed (t_{ON} : 38 ns), the DG201HS is ideally suited for high speed data acquisition requirements.

To achieve high voltage ratings and superior switching performance, the DG201HS is built on a proprietary high-voltage silicon-gate process. An epitaxial layer prevents latchup.

Each switch conducts equally well in both directions when on, and blocks input voltages to the supply values, when off.

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION



TRUTH TABLE	
Logic	Switch
0	ON
1	OFF

Logic "0" $\leq$ 0.8 V
Logic "1" $\geq$ 2.4 V

ABSOLUTE MAXIMUM RATINGS

16-Pin CerDIP ^d	900 mW
16-Pin Narrow Body SOIC and TSSOP ^e	600 mW
LCC-20 ^d	900 mW

- a. Signals on S_X , D_X , or IN_X exceeding V+ or V– will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
- b. All leads welded or soldered to PC board.
- c. Derate 6 mW/°C above 75°C.
- d. Derate 12 mW/°C above 75°C.
- e. Derate 7.6 mW/°C above 75°C.

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SPECIFICATIONS ^a									
Parameter	Symbol	Test Conditions Unless Specified V ⁺ = 15 V, V [–] = –15 V V _{IN} = 3 V, 0.8 V ^f	Temp ^b	Typ ^c	A Suffix –55 to 125°C		D Suffix –40 to 85°C		Unit
					Min ^d	Max ^d	Min ^d	Max ^d	
Analog Switch									
Analog Signal Range ^e	V _{ANALOG}		Full		V–	V+	V–	V+	V
Drain-Source On-Resistance	r _{DS(on)}	I _S = –10 mA, V _D = ±8.5 V V+ = 13.5 V, V– = –13.5 V	Room Full	25		50 75		50 75	Ω
r _{DS(on)} Match			Room	3					%
Switch Off Leakage Current	I _{S(off)}	V+ = 16.5 V, V– = –16.5 V V _D = ±15.5 V V _S = ∓15.5 V	Room Full	0.1	–1 –60	1 60	–1 –20	1 20	nA
	I _{D(off)}		Room Full	0.1	–1 –60	1 60	–1 –20	1 20	
Channel On Leakage Current	I _{D(on)}	V+ = 16.5 V, V– = –16.5 V V _S = V _D = ∓15.5 V	Room Full	0.1	–1 –60	1 60	–1 –20	1 20	
Digital Control									
Input, High Voltage	V _{INH}		Full		2.4		2.4		V
Input, Low Voltage	V _{INL}		Full			0.8		0.8	
Input Capacitance	C _{in}		Full	5					pF
Input Current	I _{INL} or I _{INH}	V _{IN} under test = 0.8 V, 3 V	Full		–1	1	–1	1	μA
Dynamic Characteristics									
Turn-On Time	t _{ON}	R _L = 1 kΩ, C _L = 35 pF V _S = ±10 V, V _{INH} = 3 V See Figure 2	Room Full	48		60 75		60 75	ns
Turn-Off Time	t _{OFF1}		Room Full	30		50 70		50 70	
	t _{OFF2}		Room	150					
Output Settling Time to 0.1%	t _s		Room	180					
Charge Injection	Q	C _L = 1 nF, V _S = 0 V V _{gen} = 0 V, R _{gen} = 0 Ω	Room	–5					pC
OFF Isolation	OIRR	R _L = 1 kΩ, C _L = 10 pF f = 100 kHz	Room	85					dB
Crosstalk (Channel-to-Channel)	X _{TALK}	Any Other Channel Switches R _L = 1 kΩ, C _L = 10 pF f = 100 kHz	Room	100					
Source Off Capacitance	C _{S(off)}	V _S , V _D = 0 V, f = 1 MHz	Room	8					pF
Drain Off Capacitance	C _{D(off)}		Room	8					
Channel On Capacitance	C _{D(on)}		Room	30					
Drain-to-Source Capacitance	C _{DS(off)}		Room	0.5					
Power Supplies									
Positive Supply Current	I ⁺	V ⁺ = 15 V, V [–] = –15 V V _{IN} = 0 or 5 V	Room Full	4.5		10		10	mA
Negative Supply Current	I [–]		Room Full	3.5	–6		–6		
Power Consumption ^c	P _C			Full			240		240

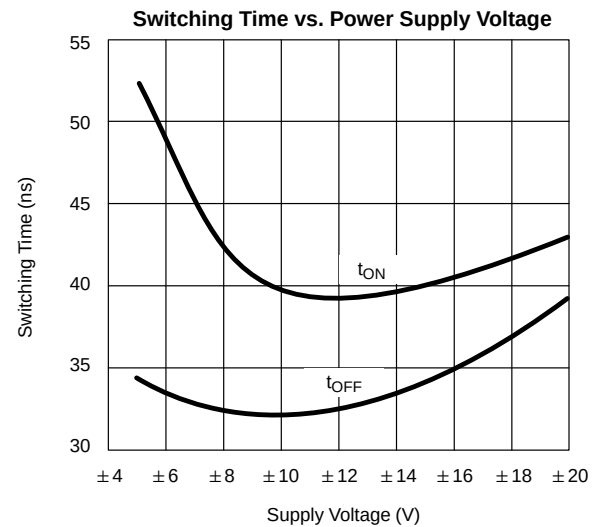
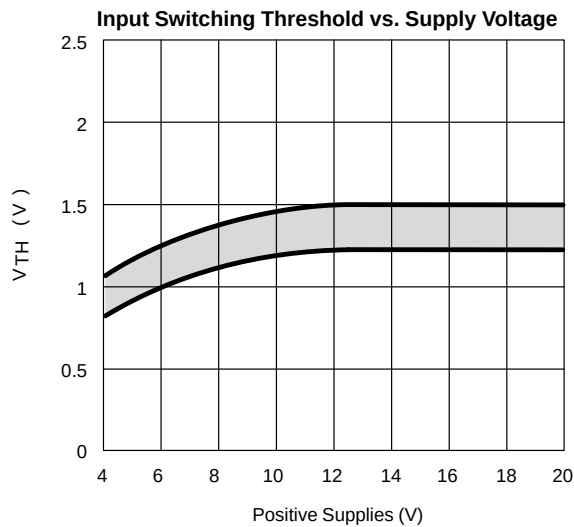
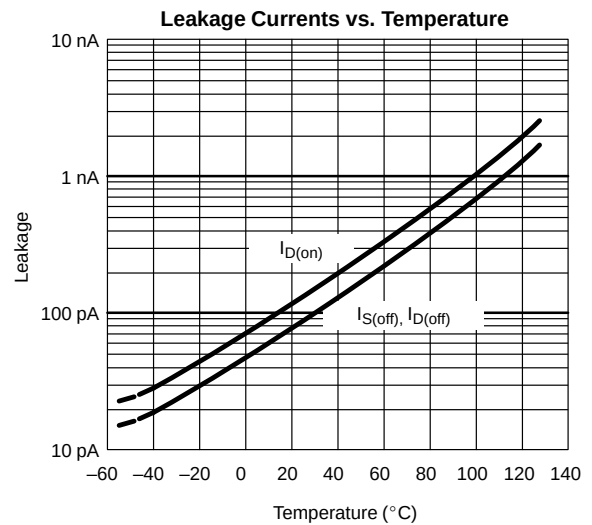
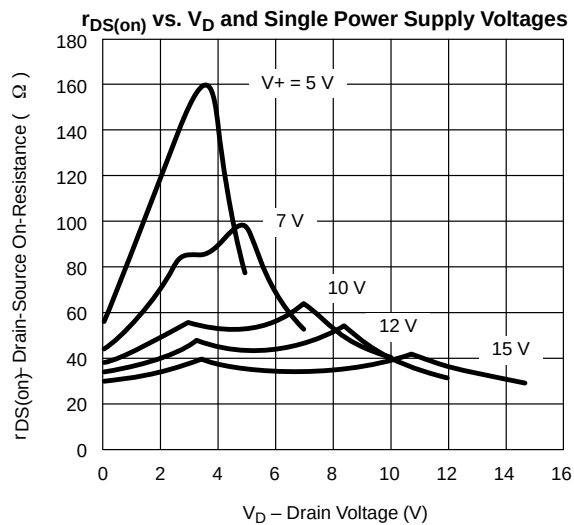
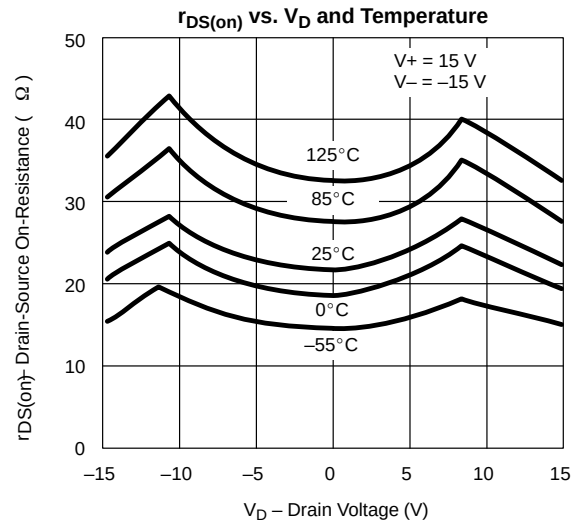
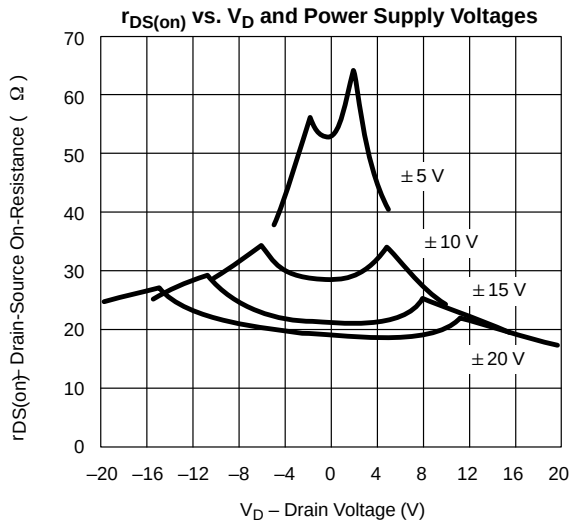
SPECIFICATIONS ^a FOR SINGLE SUPPLY									
Parameter	Symbol	Test Conditions Unless Specified V ⁺ = 10.8 V to 16.5 V V [−] = GND = 0 V V _{IN} = 3 V, 0.8 V ^f	Temp ^b	Typ ^c	A Suffix −55 to 125°C		D Suffix −40 to 85°C		Unit
					Min ^d	Max ^d	Min ^d	Max ^d	
Analog Switch									
Analog Signal Range ^e	V _{ANALOG}		Full		0	V ⁺	0	V ⁺	V
Drain-Source On-Resistance	r _{DS(on)}	I _S = −10 mA, V _D = 8.5 V V ⁺ = 10.8 V	Room Full	65		90 120		90 120	Ω
Switch Off Leakage Current	I _{S(off)}	V ⁺ = 16.5 V, V _S = 0.5 V, 10 V V _D = 10 V, 0.5 V	Room Full	0.1	−1 −60	1 60	−1 −20	1 20	nA
	I _{D(off)}		Room Full	0.1	−1 −60	1 60	−1 −20	1 20	
Channel On Leakage Current	I _{D(on)} + I _{S(on)}	V ⁺ = 16.5 V, V _D = 0.5 V, 10 V	Room Full	0.1	−1 −60	1 60	−1 −20	1 20	
Digital Control									
Input, High Voltage	V _{INH}		Full		2.4		2.4		V
Input, Low Voltage	V _{INL}		Full			0.8		0.8	
Input Capacitance	C _{in}		Full	5					pF
Input Current	I _{INL} or I _{INH}	V ⁺ = 16.5 V V _{IN} under test = 0.8 V, 3 V	Full		−1	1	−1	1	μA
Dynamic Characteristics									
Turn-On Time	t _{ON}	R _L = 1 kΩ, C _L = 35 pF, V _S = 2 V V = 10.8 V, See Figure 2	Room Full			50 70		50 70	ns
Turn-Off Time	t _{OFF1}		Room Full			50 70		50 70	
	t _{OFF2}		Room	150					
Output Settling Time to 0.1%	t _s		Room	180					
Charge Injection	Q	C _L = 1 nF, V _S = 0 V V _{gen} = 0 V, R _{gen} = 0 Ω	Room	10					pC
Off Isolation	OIRR	R _L = 1 kΩ, C _L = 10 pF f = 100 kHz	Room	85					dB
Crosstalk (Channel-to-Channel)	X _{TALK}	Any Other Channel Switches R _L = 1 kΩ, C _L = 10 pF f = 100 kHz	Room	100					
Source Off Capacitance	C _{S(off)}	f = 1 MHz	Room	10					pF
Drain Off Capacitance	C _{D(off)}		Room	10					
Channel On Capacitance	C _{D(on)}	V _{ANALOG} = 0 V	Room	30					
Power Supplies									
Positive Supply Current	I ⁺	V ⁺ = 15 V, V _{IN} = 0 or 5 V	Full			10		10	mA
Power Consumption ^c	P _C		Full			150		150	mW

Notes:

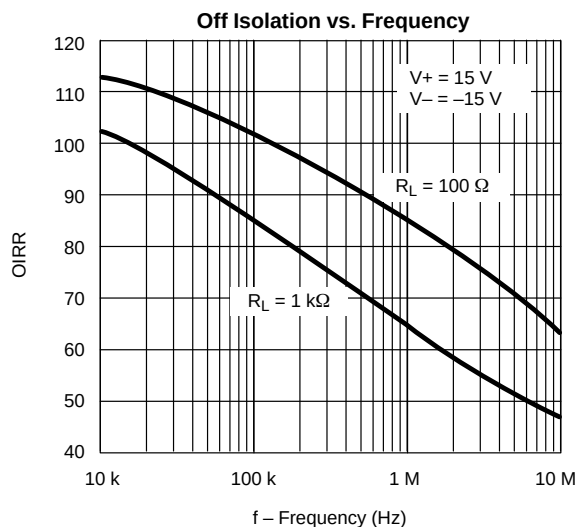
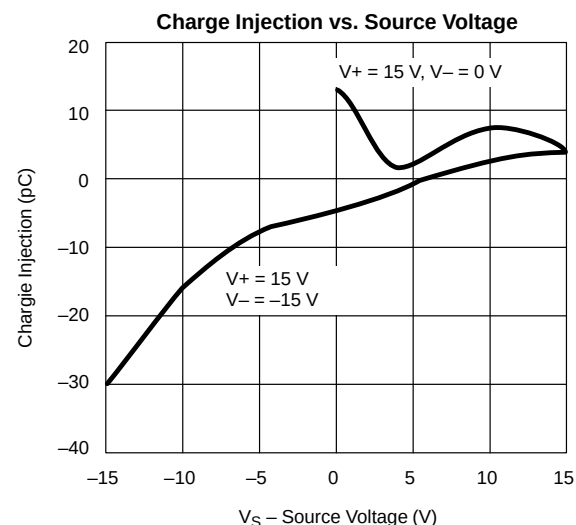
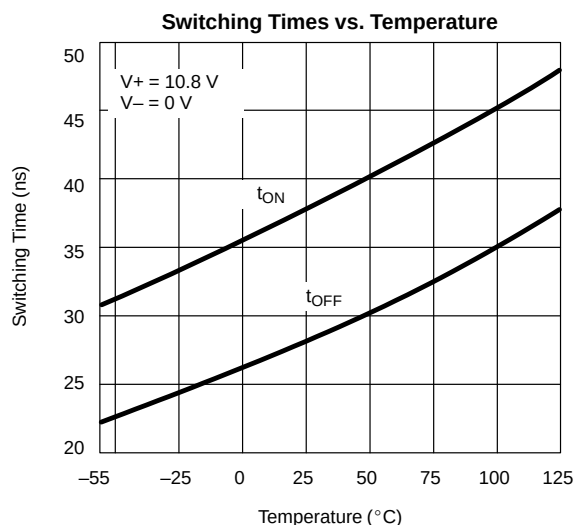
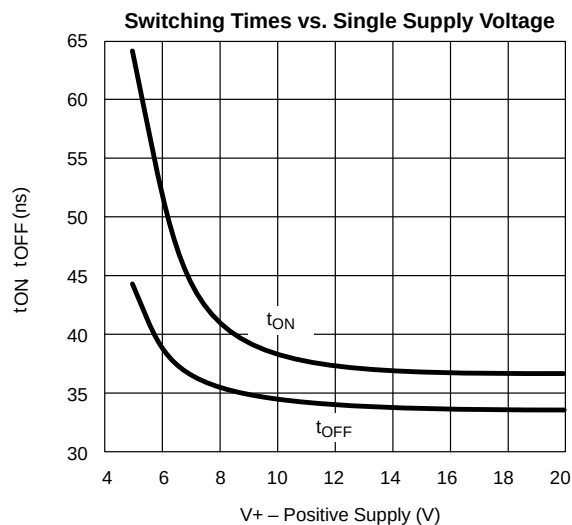
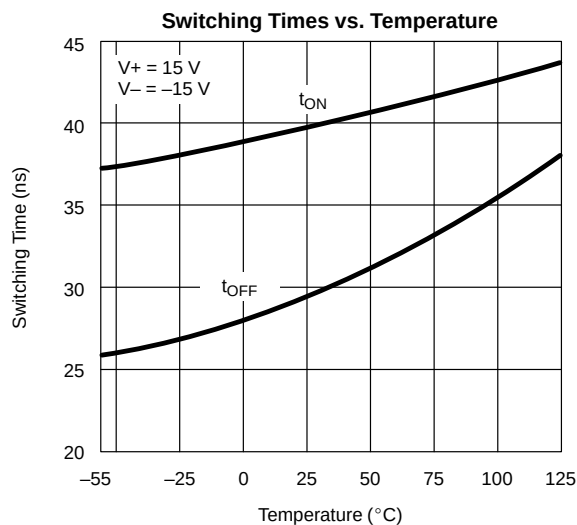
- Refer to PROCESS OPTION FLOWCHART.
- Room = 25°C, Full = as determined by the operating temperature suffix.
- Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.
- The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.
- Guaranteed by design, not subject to production test.
- V_{IN} = input voltage to perform proper function.



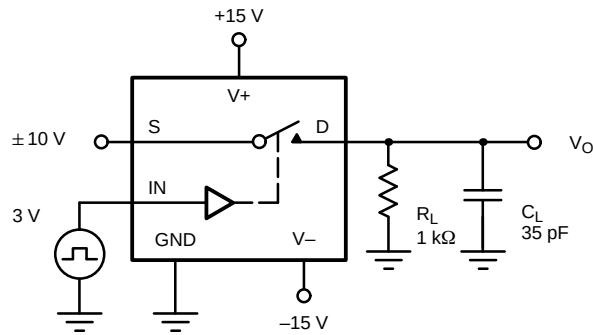
TYPICAL CHARACTERISTICS (25°C UNLESS NOTED)



TYPICAL CHARACTERISTICS (25°C UNLESS NOTED)



TEST CIRCUITS



C_L (includes fixture and stray capacitance)

$$V_O = V_S \frac{R_L}{R_L + r_{DS(on)}}$$

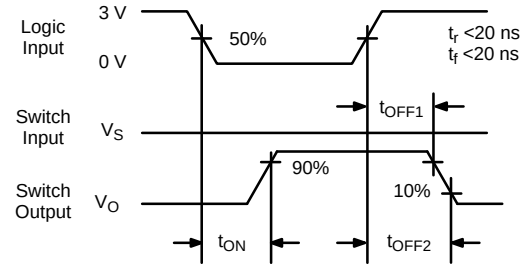
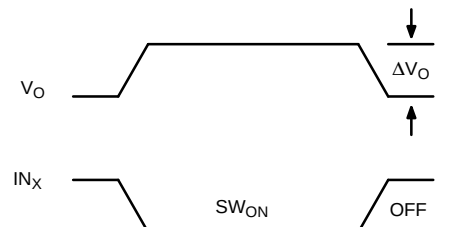
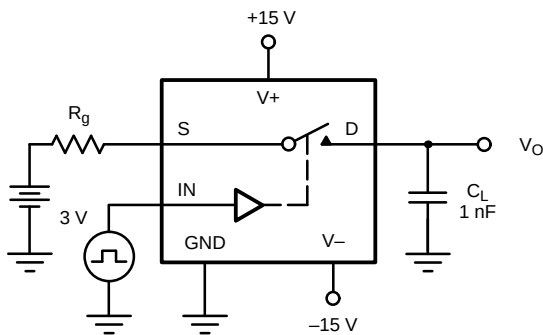
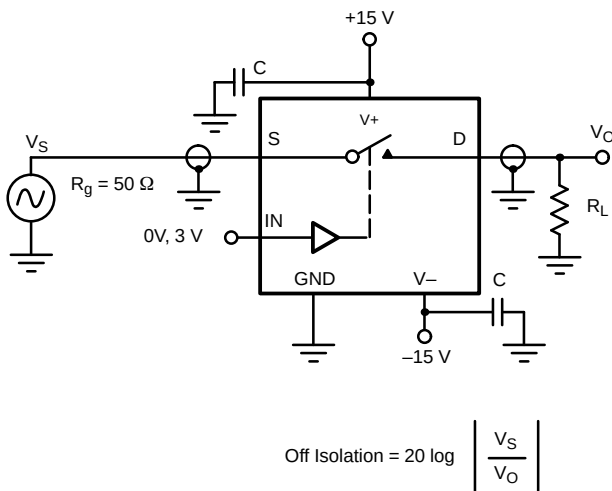


FIGURE 2. Switching Time



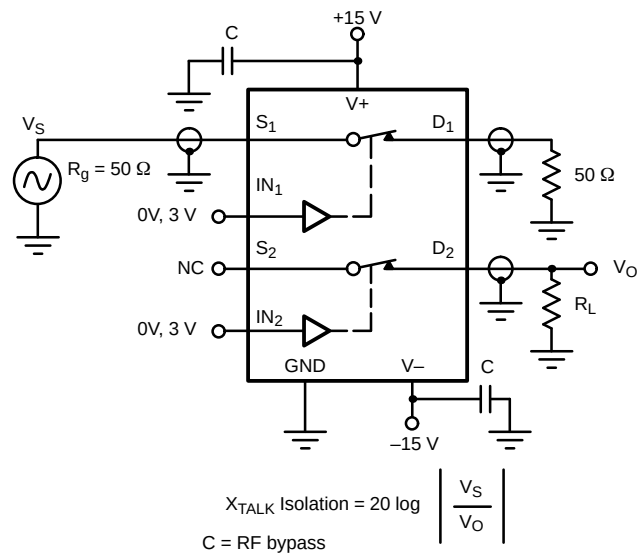
$$Q = \Delta V_O \times C_L$$

FIGURE 3. Charge Injection



$$\text{Off Isolation} = 20 \log \left| \frac{V_S}{V_O} \right|$$

FIGURE 4. Off Isolation



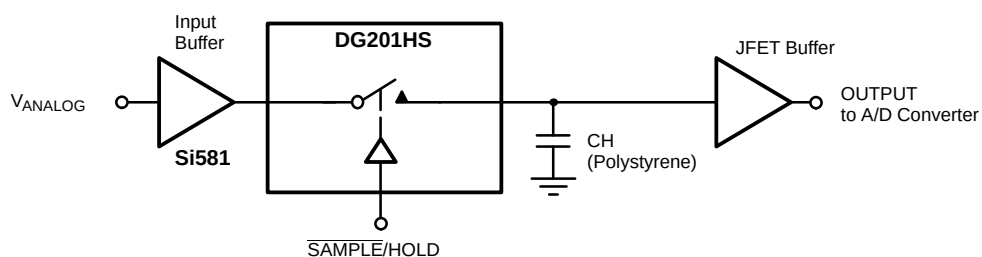
$$X_{\text{TALK}} \text{ Isolation} = 20 \log \left| \frac{V_S}{V_O} \right|$$

$C = \text{RF bypass}$

FIGURE 5. Crosstalk

APPLICATIONS

A high-speed, low-glitch analog switch such as Vishay Siliconix's DG201HS improves the accuracy and shortens the acquisition and settling times of a sample-and-hold circuit.





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